MCP (Multi-Chip Package) FLASH MEMORY & SRAM cmos

16M (×16) FLASH MEMORY & 2M (× 8) STATIC RAM

MB84VA2102-10/MB84VA2103-10

■ FEATURES

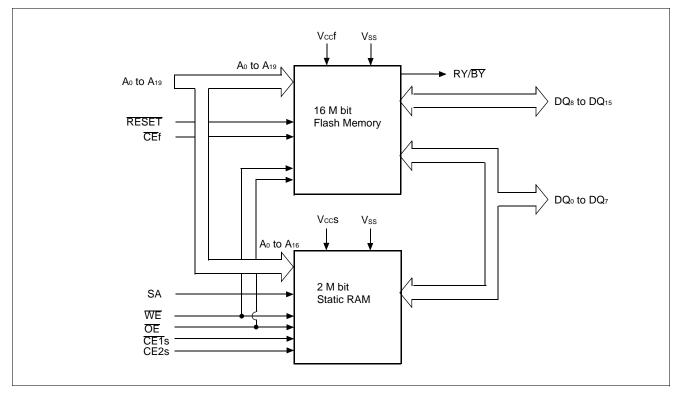
- Power supply voltage of 2.7 to 3.6 V
- High performance 100 ns maximum access time
- Operating Temperature -20 to +85°C

— FLASH MEMORY

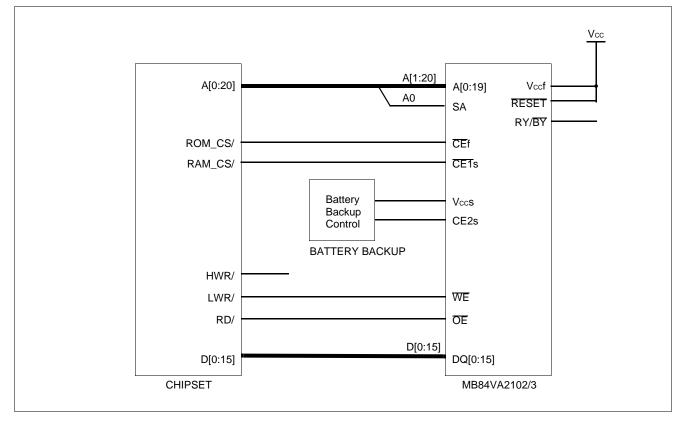
- Minimum 100,000 write/erase cycles
- Sector erase architecture One 8 K word, two 4 K words, one 16 K word, and thirty one 32 K words. Any combination of sectors can be concurrently erased. Also supports full chip erase.
- Boot Code Sector Architecture
 MB84VA2102: Top sector
 MB84VA2103: Bottom sector
- Embedded Erase[™] Algorithms Automatically pre-programs and erases the chip or any sector
- Embedded Program[™] Algorithms Automatically writes and verifies data at specified address
- Data Polling and Toggle Bit feature for detection of program or erase cycle completion
- Ready-Busy output (RY/BY)
 Hardware method for detection of program or erase cycle completion
- Automatic sleep mode When addresses remain stable, automatically switch themselves to low power mode.
- Low Vcc write inhibit \leq 2.5 V
- Erase Suspend/Resume Suspends the erase operation to allow a read in another sector within the same device Please refer to "MBM29LV160T/B" data sheet in detailed function
- SRAM
- Power dissipation
 Operating : 35 mA max.
 Standby : 50 μA max.
- Power down features using CE1s and CE2s
- Data retention supply voltage: 2.0 V to 3.6 V

Embedded Erase[™] and Embedded Program[™] are trademarks of Advanced Micro Devices, Inc.

■ BLOCK DIAGRAM



■ EXAMPLE OF CONNECTION WITH CHIPSET



■ PIN ASSIGNMENTS

	(Top View)													
	A B C D E F G H													
6	CE1s	Vss	DQ ₁	A ₁	A ₂	A4	CE2s	A9						
5	A10	DQ₅	DQ ₂	Ao	Aз	A ₇	RY/BY	A14						
4	OE	DQ7	DQ4	DQ ₀	A ₆	A ₁₈	RESET	A15						
3	A11	A ₈	A ₅	DQ8	DQ₃	DQ12	A ₁₂	A19						
2	A ₁₃	A17	SA*	<u>CE</u> f	DQ10	Vccf	DQ ₆	DQ15/A-1						
1	WE	Vccs	A16	Vss	DQ9	DQ 11	DQ13	DQ14						

*: A17 for SRAM

Table 1 Pin Configuration

Pin	Function	Input/ Output
A ₀ to A ₁₆	Address Inputs (Common)	I
A17 to A19	Address Input (Flash)	I
SA	Address Input (SRAM)	I
DQ ₀ to DQ ₇	Data Inputs/Outputs (Common)	I/O
DQ8 to DQ15	Data Inputs/Outputs (Flash)	I/O
CEf	Chip Enable (Flash)	I
CE1s	Chip Enable (SRAM)	I
CE2s	Chip Enable (SRAM)	I
ŌĒ	Output Enable (Common)	I
WE	Write Enable (Common)	I
RY/BY	Ready/Busy Outputs (Flash)	0
RESET	Hardware Reset Pin/Sector Protection Unlock (Flash)	I
N.C.	No Internal Connection	_
Vss	Device Ground (Common)	Power
Vccf	Device Power Supply (Flash)	Power
Vccs	Device Power Supply (SRAM)	Power

■ PRODUCT LINE UP

		Flash Memory	SRAM						
Ordering Part No.	$V_{\rm CC} = 3.0 \ V_{-0.3 \ V}^{+0.6 \ V}$	MB84VA2102-10/MB84VA2103-10							
Max. Address Access	Time (ns)	100	100						
Max. CE Access Time	(ns)	100	100						
Max. OE Access Time	(ns)	40	50						

■ BUS OPERATIONS

Operation (1), (3)	CEf	CE1s	CE2s	OE	WE	DQ ₀ to DQ ₇	DQ ₈ to DQ ₁₅	RESET
Full Stondby	н	Н	Х	х	х	HIGH-Z	HIGH-Z	Н
Full Standby		Х	L	^	^	nign-z	пібп-2	п
Output Disable	Х	х х х н		Н	Н	HIGH-Z	HIGH-Z	Н
Read from Flash (2)	L	Н	Х	L	н	Dout	Dout	Н
Read from Flash (2)	L	Х	L			Door	DOUT	
Write to Flash		Н	Х	Н	L	Dın	DIN	Н
	L	Х	L	11	L	DIN	DIN	
Read from SRAM	Н	L	Н	L	Н	Dout	HIGH-Z	Н
Write to SRAM	Н	L	Н	Х	L	Dın	HIGH-Z	Н
Flash Hardware Reset	x	Н	Х	х	х	HIGH-Z	HIGH-Z	I
	^	Х	L	~	^	THOIP2	111011-2	L

Table 2 User Bus Operations

Legend: $L = V_{IL}$, $H = V_{IH}$, $X = V_{IL}$ or V_{IH} . See DC Characteristics for voltage levels.

Notes: 1. Other operations except for indicated this column are inhibited.

2. WE can be $V_{\mathbb{L}}$ if \overline{OE} is $V_{\mathbb{L}}$, \overline{OE} at $V_{\mathbb{H}}$ initiates the write operations.

3. Do not apply $\overline{CE}f = V_{IL}$, $\overline{CE1}s = V_{IL}$ and $CE2s = V_{IH}$ at a time.

■ FLEXIBLE SECTOR-ERASE ARCHITECTURE on FLASH MEMORY

•One 8 K word, two 4 K words, one 16 K word, and thirty one 32 K words. •Individual-sector, multiple-sector, or bulk-erase capability.

Sector	Sector Size	Address Range
SA0	32K Words	00000H to 07FFFH
SA1	32K Words	08000H to 0FFFFH
SA2	32K Words	10000H to 17FFFH
SA3	32K Words	18000H to 1FFFFH
SA4	32K Words	20000H to 27FFFH
SA5	32K Words	28000H to 2FFFFH
SA6	32K Words	30000H to 37FFFH
SA7	32K Words	38000H to 3FFFFH
SA8	32K Words	40000H to 47FFFH
SA9	32K Words	48000H to 4FFFFH
SA10	32K Words	50000H to 57FFFH
SA11	32K Words	58000H to 5FFFFH
SA12	32K Words	60000H to 67FFFH
SA13	32K Words	68000H to 6FFFFH
SA14	32K Words	70000H to 77FFFH
SA15	32K Words	78000H to 7FFFFH
SA16	32K Words	80000H to 87FFFH
SA17	32K Words	88000H to 8FFFFH
SA18	32K Words	90000H to 97FFFH
SA19	32K Words	98000H to 9FFFFH
SA20	32K Words	A0000H to A7FFFH
SA21	32K Words	A8000H to AFFFFH
SA22	32K Words	B0000H to B7FFFH
SA23	32K Words	B8000H to BFFFFH
SA24	32K Words	C0000H to C7FFFH
SA25	32K Words	C8000H to CFFFFH
SA26	32K Words	D0000H to D7FFFH
SA27	32K Words	D8000H to DFFFFH
SA28	32K Words	E0000H to E7FFFH
SA29	32K Words	E8000H to EFFFFH
SA30	32K Words	F0000H to F7FFFH
SA31	16K Words	F8000H to FBFFFH
SA32	4K Words	FC000H to FCFFFH
SA33	4K Words	FD000H to FDFFFH
SA34	8K Words	FE000H to FFFFFH

Sector Sector Size Address Range SA0 8K Words 00000H to 01FFFH SA1 4K Words 02000H to 03FFFH SA2 4K Words 03000H to 03FFFH SA3 16K Words 04000H to 07FFFH SA4 32K Words 08000H to 07FFFH SA5 32K Words 18000H to 17FFFH SA6 32K Words 20000H to 27FFFH SA8 32K Words 28000H to 27FFFH SA8 32K Words 28000H to 37FFFH SA10 32K Words 38000H to 37FFFH SA11 32K Words 38000H to 37FFFH SA10 32K Words 38000H to 37FFFH SA11 32K Words 38000H to 57FFFH SA12 32K Words 50000H to 57FFFH SA13 32K Words 58000H to 67FFFH SA14 32K Words 68000H to 67FFFH SA16 32K Words 78000H to 77FFFH SA16 32K Words 8000H to 87FFFH SA20 32K Words 88000H to 87FFFH	Costor	Sector Cine	Addrogo Dongo
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SA2032K Words88000H to 8FFFHSA2132K Words90000H to 97FFFHSA2232K Words98000H to 97FFFHSA2332K WordsA0000H to 97FFFHSA2332K WordsA0000H to A7FFFHSA2432K WordsA8000H to A7FFFHSA2532K WordsB0000H to B7FFFHSA2632K WordsB8000H to B7FFFHSA2732K WordsC0000H to C7FFFHSA2832K WordsC8000H to D7FFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to E7FFFHSA3132K WordsE8000H to E7FFFHSA3232K WordsF0000H to F7FFFH	SA18	32K Words	78000H to 7FFFFH
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SA2232K Words98000H to 9FFFHSA2332K WordsA0000H to A7FFFHSA2432K WordsA8000H to A7FFFHSA2532K WordsB0000H to B7FFFHSA2632K WordsB8000H to B7FFFHSA2732K WordsC0000H to C7FFFHSA2832K WordsC8000H to D7FFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to E7FFFHSA3332K WordsF0000H to F7FFFH	SA20	32K Words	88000H to 8FFFFH
SA2332K WordsA0000H to A7FFFHSA2432K WordsA8000H to AFFFFHSA2532K WordsB0000H to B7FFFHSA2632K WordsB8000H to BFFFFHSA2732K WordsC0000H to C7FFFHSA2832K WordsC8000H to D7FFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to E7FFFHSA3332K WordsF0000H to F7FFFH	SA21	32K Words	90000H to 97FFFH
SA2432K WordsA8000H to AFFFFHSA2532K WordsB0000H to B7FFFHSA2632K WordsB8000H to BFFFFHSA2732K WordsC0000H to C7FFFHSA2832K WordsC8000H to CFFFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to EFFFFHSA3332K WordsF0000H to F7FFFH	SA22	32K Words	98000H to 9FFFFH
SA2532K WordsB0000H to B7FFFHSA2632K WordsB8000H to BFFFFHSA2732K WordsC0000H to C7FFFHSA2832K WordsC8000H to CFFFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to E7FFFHSA3332K WordsF0000H to F7FFFH	SA23	32K Words	A0000H to A7FFFH
SA2632K WordsB8000H to BFFFHSA2732K WordsC0000H to C7FFFHSA2832K WordsC8000H to CFFFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to EFFFFHSA3332K WordsF0000H to F7FFFH	SA24	32K Words	A8000H to AFFFFH
SA2732K WordsC0000H to C7FFFHSA2832K WordsC8000H to CFFFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to EFFFFHSA3332K WordsF0000H to F7FFFH	SA25	32K Words	B0000H to B7FFFH
SA2832K WordsC8000H to CFFFHSA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to EFFFFHSA3332K WordsF0000H to F7FFFH	SA26	32K Words	B8000H to BFFFFH
SA2932K WordsD0000H to D7FFFHSA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to EFFFFHSA3332K WordsF0000H to F7FFFH	SA27	32K Words	C0000H to C7FFFH
SA3032K WordsD8000H to DFFFFHSA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to EFFFFHSA3332K WordsF0000H to F7FFFH	SA28	32K Words	C8000H to CFFFFH
SA3132K WordsE0000H to E7FFFHSA3232K WordsE8000H to EFFFFHSA3332K WordsF0000H to F7FFFH	SA29	32K Words	D0000H to D7FFFH
SA3232K WordsE8000H to EFFFHSA3332K WordsF0000H to F7FFFH		32K Words	D8000H to DFFFFH
SA33 32K Words F0000H to F7FFH	SA31	32K Words	E0000H to E7FFFH
	SA32	32K Words	E8000H to EFFFFH
	SA33	32K Words	F0000H to F7FFFH
	SA34	32K Words	F8000H to FFFFFH

MB84VA2102 Sector Architecture

MB84VA2103 Sector Architecture

Sector Address	A 19	A 18	A 17	A 16	A 15	A 14	A 13	A 12	Address Range
SA0	0	0	0	0	0	Х	Х	Х	00000H to 07FFFH
SA1	0	0	0	0	1	Х	Х	Х	08000H to 0FFFH
SA2	0	0	0	1	0	Х	Х	Х	10000H to 17FFFH
SA3	0	0	0	1	1	Х	Х	Х	18000H to 1FFFH
SA4	0	0	1	0	0	Х	Х	Х	20000H to 27FFFH
SA5	0	0	1	0	1	Х	Х	Х	28000H to 2FFFH
SA6	0	0	1	1	0	Х	Х	Х	30000H to 37FFFH
SA7	0	0	1	1	1	Х	Х	Х	38000H to 3FFFFH
SA8	0	1	0	0	0	Х	Х	Х	40000H to 47FFFH
SA9	0	1	0	0	1	Х	Х	Х	48000H to 4FFFH
SA10	0	1	0	1	0	Х	Х	Х	50000H to 57FFFH
SA11	0	1	0	1	1	Х	Х	Х	58000H to 5FFFH
SA12	0	1	1	0	0	Х	Х	Х	60000H to 67FFH
SA13	0	1	1	0	1	Х	Х	Х	68000H to 6FFFH
SA14	0	1	1	1	0	Х	Х	Х	70000H to 77FFFH
SA15	0	1	1	1	1	Х	Х	Х	78000H to 7FFFH
SA16	1	0	0	0	0	Х	Х	Х	80000H to 87FFFH
SA17	1	0	0	0	1	Х	Х	Х	88000H to 8FFFH
SA18	1	0	0	1	0	Х	Х	Х	90000H to 97FFFH
SA19	1	0	0	1	1	Х	Х	Х	98000H to 9FFFH
SA20	1	0	1	0	0	Х	Х	Х	A0000H to A7FFFH
SA21	1	0	1	0	1	Х	Х	Х	A8000H to AFFFH
SA22	1	0	1	1	0	Х	Х	Х	B0000H to B7FFFH
SA23	1	0	1	1	1	Х	Х	Х	B8000H to BFFFH
SA24	1	1	0	0	0	Х	Х	Х	C0000H to C7FFFH
SA25	1	1	0	0	1	Х	Х	Х	C8000H to CFFFFH
SA26	1	1	0	1	0	Х	Х	Х	D0000H to D7FFFH
SA27	1	1	0	1	1	Х	Х	Х	D8000H to DFFFFH
SA28	1	1	1	0	0	Х	Х	Х	E0000H to E7FFFH
SA29	1	1	1	0	1	Х	Х	Х	E8000H to EFFFH
SA30	1	1	1	1	0	Х	Х	Х	F0000H to F7FFFH
SA31	1	1	1	1	1	0	Х	Х	F8000H to FBFFFH
SA32	1	1	1	1	1	1	0	0	FC000H to FCFFFH
SA33	1	1	1	1	1	1	0	1	FD000H to FDFFFH
SA34	1	1	1	1	1	1	1	Х	FE000H to FFFFH

Table 3 Sector Address Tables (MB84VA2102)

Sector Address	A 19	A 18	A 17	A 16	A 15	A 14	A 13	A 12	Address Range
SA0	0	0	0	0	0	0	0	Х	00000H to 01FFFH
SA1	0	0	0	0	0	0	1	0	02000H to 02FFFH
SA2	0	0	0	0	0	0	1	1	03000H to 03FFFH
SA3	0	0	0	0	0	1	0	Х	04000H to 07FFFH
SA4	0	0	0	0	1	Х	Х	Х	08000H to 0FFFFH
SA5	0	0	0	1	0	Х	Х	Х	10000H to 17FFFH
SA6	0	0	0	1	1	Х	Х	Х	18000H to 1FFFFH
SA7	0	0	1	0	0	Х	Х	Х	20000H to 27FFFH
SA8	0	0	1	0	1	Х	Х	Х	28000H to 2FFFFH
SA9	0	0	1	1	0	Х	Х	Х	30000H to 37FFFH
SA10	0	0	1	1	1	Х	Х	Х	38000H to 3FFFFH
SA11	0	1	0	0	0	Х	Х	Х	40000H to 47FFFH
SA12	0	1	0	0	1	Х	Х	Х	48000H to 4FFFFH
SA13	0	1	0	1	0	Х	Х	Х	50000H to 57FFFH
SA14	0	1	0	1	1	Х	Х	Х	58000H to 5FFFFH
SA15	0	1	1	0	0	Х	Х	Х	60000H to 67FFFH
SA16	0	1	1	0	1	Х	Х	Х	68000H to 6FFFFH
SA17	0	1	1	1	0	Х	Х	Х	70000H to 77FFFH
SA18	0	1	1	1	1	Х	Х	Х	78000H to 7FFFFH
SA19	1	0	0	0	0	Х	Х	Х	80000H to 87FFFH
SA20	1	0	0	0	1	Х	Х	Х	88000H to 8FFFFH
SA21	1	0	0	1	0	Х	Х	Х	90000H to 97FFFH
SA22	1	0	0	1	1	Х	Х	Х	98000H to 9FFFFH
SA23	1	0	1	0	0	Х	Х	Х	A0000H to A7FFFH
SA24	1	0	1	0	1	Х	Х	Х	A8000H to 8FFFFH
SA25	1	0	1	1	0	Х	Х	Х	B0000H to B7FFFH
SA26	1	0	1	1	1	Х	Х	Х	B8000H to BFFFFH
SA27	1	1	0	0	0	Х	Х	Х	C0000H to C7FFFH
SA28	1	1	0	0	1	Х	Х	Х	C8000H to CFFFFH
SA29	1	1	0	1	0	Х	Х	Х	D0000H to D7FFFH
SA30	1	1	0	1	1	Х	Х	Х	D8000H to DFFFFH
SA31	1	1	1	0	0	Х	Х	Х	E0000H to E7FFFH
SA32	1	1	1	0	1	Х	Х	Х	E8000H to EFFFFH
SA33	1	1	1	1	0	Х	Х	Х	F0000H to F7FFFH
SA34	1	1	1	1	1	Х	Х	Х	F8000H to FFFFFH

Table 4 Sector Address Tables (MB84VA2103)

Table 5. 1	Flash Memory	Autoselect Codes
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	Туре	A ₆	A 1	A	Code (HEX)
Manufacturer's Co	de	VIL	VIL	VIL	04H
Device Code	MB84VA2102	VIL	VIL	Vін	22C4H
	MB84VA2103	VIL	VIL	Vін	2249H

Table 5. 2 Expanded Autoselect Code Table

	Code	DQ 15	DQ ₁₄	DQ 13	DQ ₁₂	DQ 11	DQ 10	DQ₃	DQଃ	DQ7	DQ ₆	DQ₅	DQ4	DQ₃	DQ ₂	DQ ₁	DQ₀	
Manufactu	04H	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	
Device	MB84VA2102	22C4H	0	0	1	0	0	0	1	0	1	1	0	0	0	1	0	0
Code	MB84VA2103	2249H	0	0	1	0	0	0	1	0	0	1	0	0	1	0	0	1

Command Sequence	Bus Write Cycles	First Bus Write Cycle		Second Write (Third Bus Write Cycle		Fourth Bus Read/Write Cycle		Fifth Bus Write Cycle		Sixth Bus Write Cycle			
•	Req'd	Addr.	Data	Addr.	Data	Addr.	Data	Addr.	Data	Addr.	Data	Addr.	Data		
Read/Reset	1	XXXH	F0H	_	—	—	—	_	—	_	—	—	—		
Read/Reset	3	555H	AAH	2AAH	55H	555H	F0H	RA	RD			—	_		
Autoselect	3	555H	AAH	2AAH	55H	555H	90H		—		_		_		
Program	4	555H	AAH	2AAH	55H	555H	A0H	PA	PD		_		_		
Chip Erase	6	555H	AAH	2AAH	55H	555H	80H	555H	AAH	2AAH	55H	555H	10H		
Sector Erase	6	555H	AAH	2AAH	55H	555H	80H	555H	AAH	2AAH	55H	SA	30H		
Sector Erase Suspe	end	Erase ca	Erase can be suspended during sector erase with Addr. ("H" or "L"). Data (B0H)												
Sector Erase Resur	ne	Erase ca	Erase can be resumed after suspend with Addr. ("H" or "L"). Data (30H)												
Set to Fast Mode	3	555H	AAH	2AAH	55H	555H	20H	_	_	_	_	_			
Fast Program (Note)	2	хххн	A0H	PA	PD	_	_	_		_	_	_			
Reset from Fast Mode (Note)	2	ХХХН	90H	XXXH	F0H	_	_	_	_	_	_	_			
Extended Sector Protect	4	ХХХН	60H	SPA	60H	SPA	40H	SPA	SD						

 Table 6
 Flash Memory Command Definitions

Address bits A_{11} to $A_{20} = X =$ "H" or "L" for all address commands except for Program Address (PA) and Sector Address (SA).

Bus operations are defined in Table 2.

Both Read/Reset commands are functionally equivalent, resetting the device to the read mode.

RA =Address of the memory location to be read.

- PA =Address of the memory location to be programmed. Addresses are latched on the falling edge of the write pulse.
- SA =Address of the sector to be erased. The combination of A₂₀, A₁₉, A₁₈, A₁₇, A₁₆, A₁₅, A₁₄, and A₁₃ will uniquely select any sector.
- RD =Data read from location RA during read operation.
- PD =Data to be programmed at location PA.
- SPA =Sector address to be protected. Set sector address (SA) and $(A_6, A_1, A_0) = (0, 1, 0)$.
- SD =Sector protection verify data. Output 01H at protected sector addresses and output 00H at unprotected sector addresses.

Note: This command is valid while Fast Mode.

■ ABSOLUTE MAXIMUM RATINGS

Storage Temperature	–55°C to +125°C
Ambient Temperature with Power Applied	–25°C to +85°C
Voltage with Respect to Ground All pins (Note)	–0.3 V to Vccf +0.5 V
	–0.3 V to Vccs +0.5 V
Vccf/Vccs Supply (Note)	–0.3 V to +4.6 V

Note: Minimum DC voltage on input or I/O pins are –0.5 V. During voltage transitions, inputs may negative overshoot Vss to –2.0 V for periods of up to 20 ns. Maximum DC voltage on output and I/O pins are Vccf +0.5 V or Vccs +0.5 V. During voltage transitions, outputs may positive overshoot to Vcc +2.0 V for periods of up to 20 ns.

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

RECOMMENDED OPERATING RANGES

Commercial Devices	
Ambient Temperature (TA)	–20°C to +85°C
Vccf/Vccs Supply Voltages	+2.7 V to +3.6 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

■ DC CHARACTERISTICS

Parameter Symbol	Parameter Description	Те	est Condit	ions	Min.	Тур.	Max.	Unit												
lu	Input Leakage Current	—		-1.0	_	+1.0	μΑ													
Ilo	Output Leakage Current		—		-1.0		+1.0	μΑ												
lcc₁f			$V_{CC}f = V_{CC} Max., \overline{CE}f = V_{IL} \frac{t_{CYCLE} = 10 \text{ MHz}}{t_{CYCLE} = 5 \text{ MHz}}$				35	mA												
	(Read)	OE = VIH			—	—	17													
lcc2f	Flash Vcc Active Current (Program/Erase)	Vccf = Vcc Max	., CE f = V	IL, OE = VIH	—	—	35	mA												
Icc1S	SRAM Vcc Active		Vccs = Vcc Max., tcycle =10 MHz				40	mA												
10013	Current	CE1s = V⊩, CE	2s = V⊮	tcycle = 1 MHz			12	mA												
Icc2S	SRAM Vcc Active	$\overline{CE1s} = 0.2 V,$ CE2s = Vccs -	021/	tcycle = 10 MHz	—	—	35	mA												
10023	Current	$\overline{WE} = Vccs - 0.$		tcycle = 1 MHz	—		6	mA												
Isb1f	Flash Vcc Standby Current	Vccf = Vcc Max RESET = Vccf :		cf ± 0.3 V		_	5	μΑ												
Isb2f	Flash Vcc Standby Current (RESET)	Vccf = Vcc Max	., RESET	= Vss ± 0.3 V		_	5	μA												
SB1S	SRAM Vcc Standby Current	CE1s = V⊮ or C	CE2s = Vı∟			_	2	mA												
		CE1s = Vcc - 0.2 V or CE2s	Vccs =	T _A = 25°C		1	2.5	μΑ												
															3.0 V ±10%	T _A = −20 to +85°C		_	55	μA
			Vccs =	$T_A = 25^{\circ}C$		1.5	3	μΑ												
I SB2 S**	SRAM Vcc Standby Current		3.3 V ±0.3 V	T _A = −20 to +85°C		_	60	μΑ												
		= 0.2 V		$T_A = 25^{\circ}C$		1	2	μΑ												
			Vccs = 3.0 V	T _A = −20 to +40°C	_	_	5	μΑ												
				T _A = −20 to +85°C	—	_	50	μA												
VIL	Input Low Level	· - ·			-0.3		0.6	V												
VIH	Input High Level			2.2		Vcc+0.3*	V													
Vol	Output Low Voltage Level	Io∟ = 2.1 mA, Vccf = Vccs = Vcc Min.			_	0.4	V													
Vон	Output High Voltage Level	Iон = -500μ A, Vccf = Vccs = Vcc Min.		Vcc-0.5		_	V													
Vlko	Flash Low Vcc Lock-Out Voltage				2.3	_	2.5	V												

*: Vcc indicate lower of Vccf or Vccs

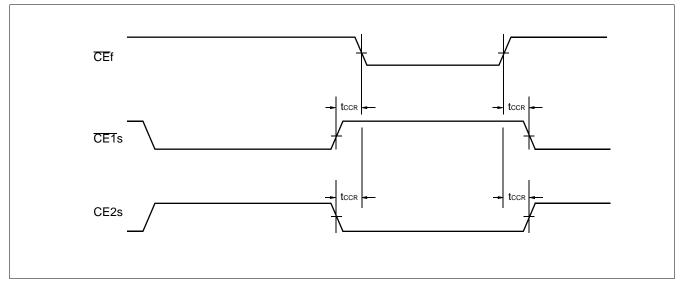
** :During standby mode with $\overline{CE1}s = V_{CCS} - 0.2$ V, CE2s should be CE2s < 0.2V or CE2s > $V_{CCS} - 0.2$ V

■ AC CHARACTERISTICS

• CE Timing

Parameter Symbols		Description	Test Se	etup	-10	Unit
JEDEC	Standard					
—	t CCR	CE Recover Time	—	Min.	0	ns

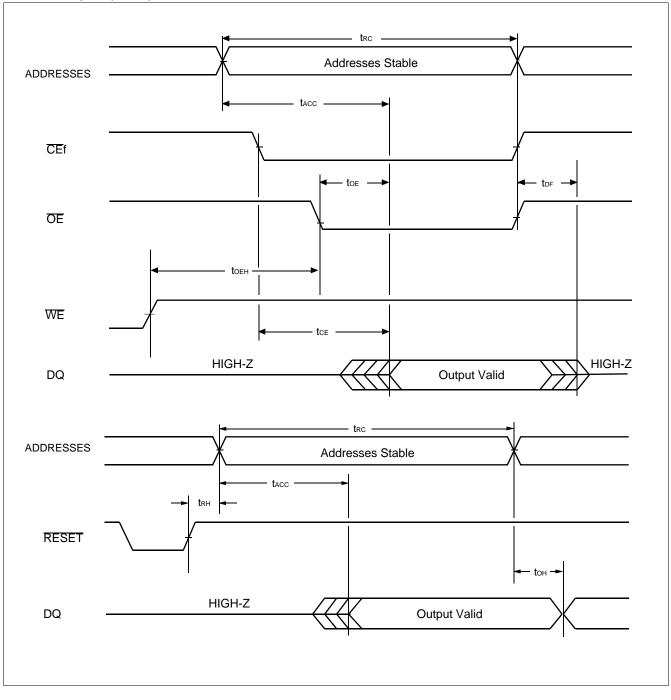
• Timing Diagram for alternating SRAM to Flash



• Read Only Operations Characteristics (Flash)

Parameter Symbols		Description	Test	-10 (Note)		Unit		
JEDEC	Standard		Setup		Mi		Max.	
t avav	t RC	Read Cycle Time	_	100	—	ns		
t Ανqν	tacc	Address to Output Delay	$\frac{\overline{CE}f = V_{IL}}{OE} = V_{IL}$		100	ns		
t elqv	tcef	Chip Enable to Output Delay	$\overline{OE} = V_{IL}$	_	100	ns		
t GLQV	toe	Output Enable to Output Delay	—	_	40	ns		
t ehqz	tdf	Chip Enable to Output High-Z	—	_	30	ns		
t _{GHQZ}	tdf	Output Enable to Output High-Z	—	_	30	ns		
taxqx	tон	Output Hold Time From Addresses, CEf or OE, Whichever Occurs First	_	0	_	ns		
_	t READY	RESET Pin Low to Read Mode		_	20	μs		

Note: Test Conditions–Output Load: 1 TTL gate and 30 pF Input rise and fall times: 5 ns Input pulse levels: 0.0 V to 3.0 V Timing measurement reference level Input: 1.5 V Output: 1.5 V • Read Cycle (Flash)



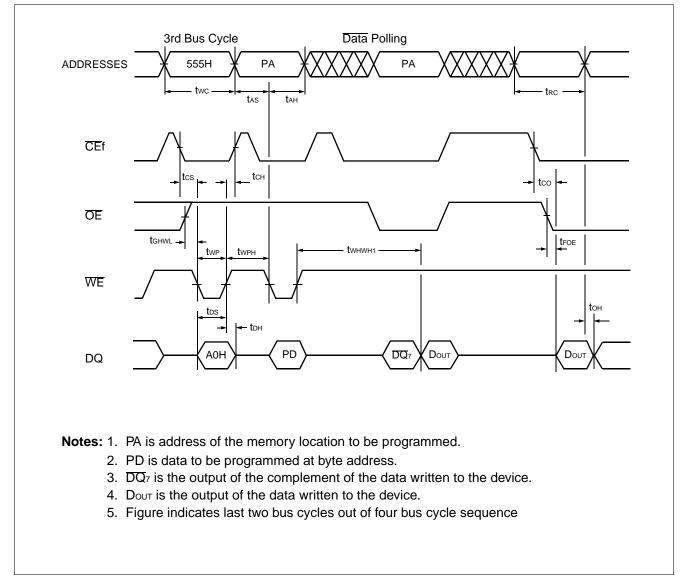
• Erase/Program Operations (Flash)

Parameter Symbols		Description			Unit		
JEDEC	Standard	Description		Min.	Тур.	Max.	
t avav	twc	Write Cycle Time		100	—	_	ns
t avwl	tas	Address Setup Time (WE to	o Addr.)	0	—		ns
t avel	tas	Address Setup Time (CEf to	o Addr.)	0	—		ns
twlax	tан	Address Hold Time (WE to	Addr.)	50	_	_	ns
t elax	tан	Address Hold Time (CEf to	Addr.)	50	_	_	ns
t d∨wн	tos	Data Setup Time		50	_	_	ns
t whdx	t _{DH}	Data Hold Time		0	_	_	ns
—	toes	Output Enable Setup Time		0	—		ns
	R Output Eachla Hald Time	Read	0	_	_	ns	
_	tоен	Output Enable Hold Time	Toggle and Data Polling	10	_	_	ns
t GHEL	t GHEL	Read Recover Time Before	Write (OE to CEf)	0		_	ns
t GHWL	t GHWL	Read Recover Time Before	Write (OE to WE)	0	_	_	ns
twlel	tws	WE Setup Time (CEf to WE	:)	0	—		ns
t elwl	tcs	CEf Setup Time (WE to CE	f)	0		_	ns
tенwн	twн	WE Hold Time (CEf to WE)		0		_	ns
t wheh	tсн	CEf Hold Time (WE to CEf)		0		_	ns
t wlwh	twp	Write Pulse Width		50		_	ns
t eleh	tср	CEf Pulse Width		50		_	ns
twhwl	twpн	Write Pulse Width High		30		_	ns
tehel	tсрн	CEf Pulse Width High		30		_	ns
t whwh1	twhwh1	Programming Operation			16	_	μs
		Contar France Operation (No	4. 1)		1		sec
t whwh2	twhwh2	Sector Erase Operation (No	ne i)		_	15	sec
	tvcs	Vccf Setup Time		50			μs
_	tvlh⊤	Voltage Transition Time (No	ote 2)	4		_	μs
	tvidr	Rise Time to V _{ID} (Note 2)		500	_	_	ns
	t _{RB}	Recover Time from RY/BY		0	_	_	ns
	t _{RP}	RESET Pulse Width		500			ns
	t _{RH}	RESET Hold Time Before Read		200	_	_	ns
	teoe	Delay Time from Embedded	d Output Enable	_		100	ns
_	t BUSY	Program/Erase Valid to RY/	BY Delay	_		90	ns

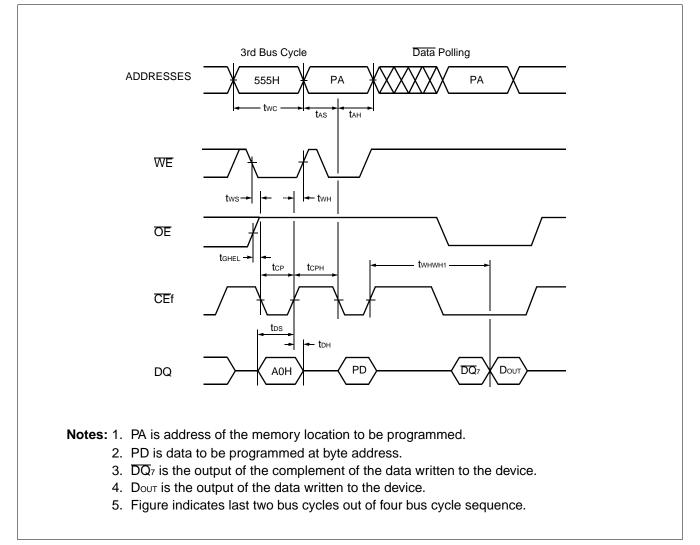
Note : 1. This does not include the preprogramming time.

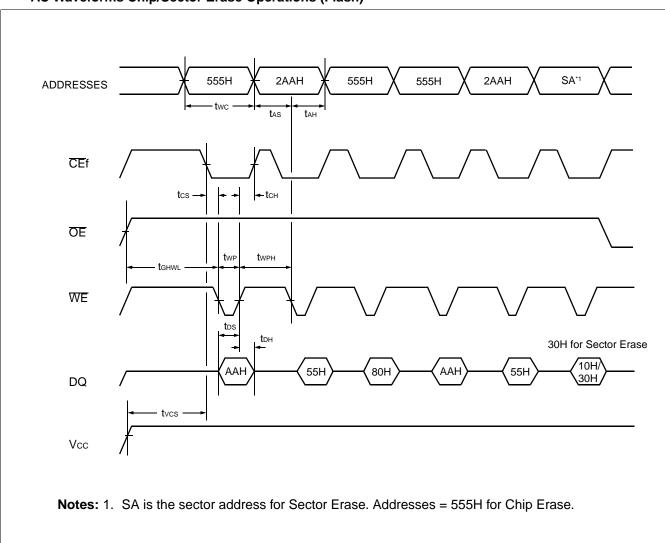
2. This timing is for Sector Protection Operation.

• Write Cycle (WE control) (Flash)

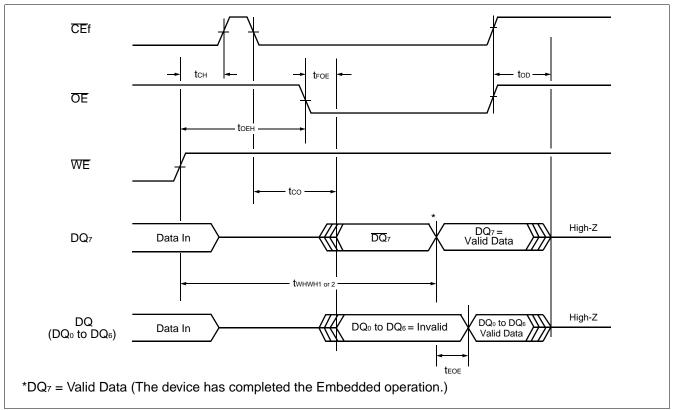


• Write Cycle (CEf control) (Flash)



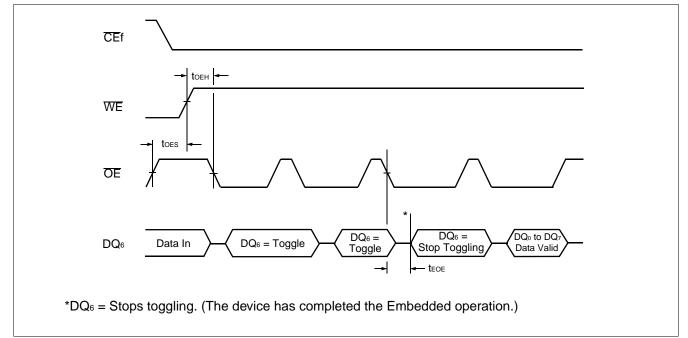


• AC Waveforms Chip/Sector Erase Operations (Flash)

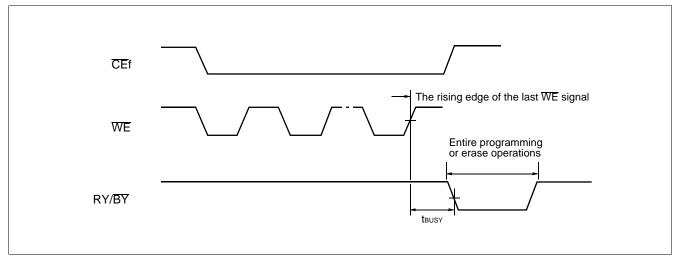


• AC Waveforms for Data Polling during Embedded Algorithm Operations (Flash)

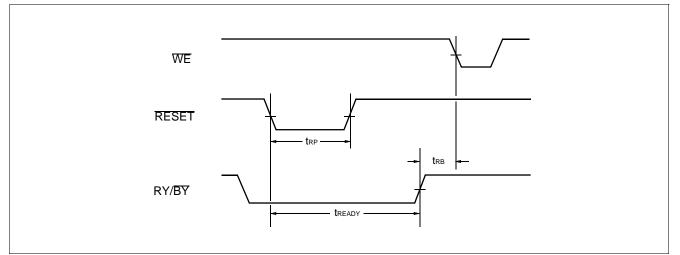
• AC Waveforms for Toggle Bit during Embedded Algorithm Operations (Flash)



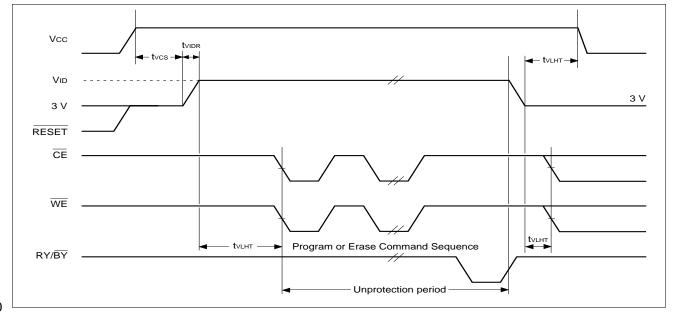
• RY/BY Timing Diagram during Write/Erase Operations (Flash)



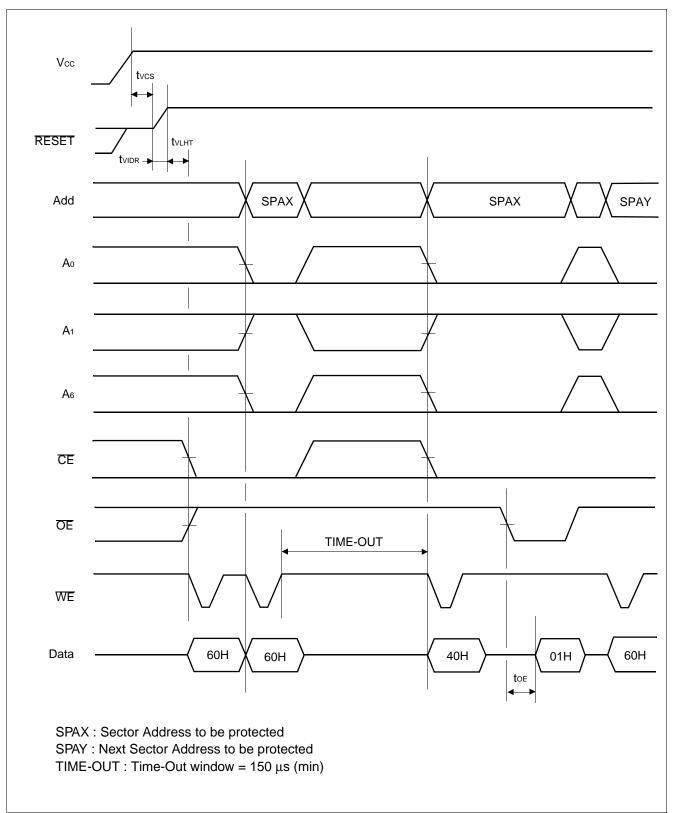
• RESET, RY/BY Timing Diagram (Flash)



• Temporary Sector Unprotection (Flash)



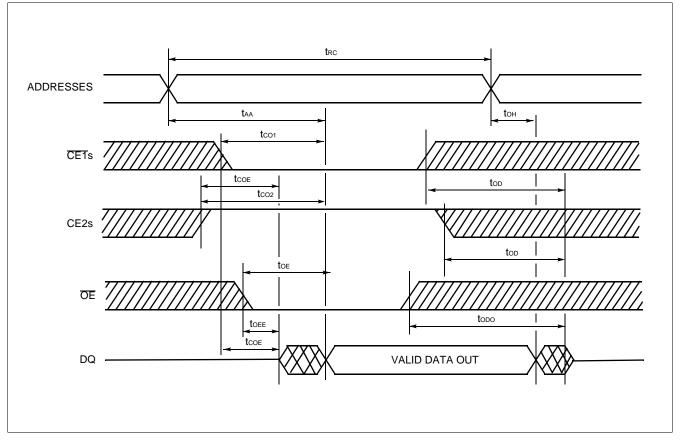
• Extended Sector Protection (Flash)



• Read Cycle (SRAM)

Parameter Symbol	Parameter Description	Min.	Max.	Unit
trc	Read Cycle Time	100	—	ns
t AA	Address Access Time	—	100	ns
tco1	Chip Enable (CE1s) Access Time	_	100	ns
tco2	Chip Enable (CE2s) Access Time	_	100	ns
toe	Output Enable Access Time	_	50	ns
t COE	Chip Enable (CE1s Low and CE2s High) to Output Active	5	_	ns
toee	Output Enable Low to Output Active	0	_	ns
top	Chip Enable (CE1s High or CE2s Low) to Output High-Z	_	40	ns
todo	Output Enable High to Output High-Z	—	40	ns
tон	Output Data Hold Time	10	_	ns

• Read Cycle (Note 1) (SRAM)

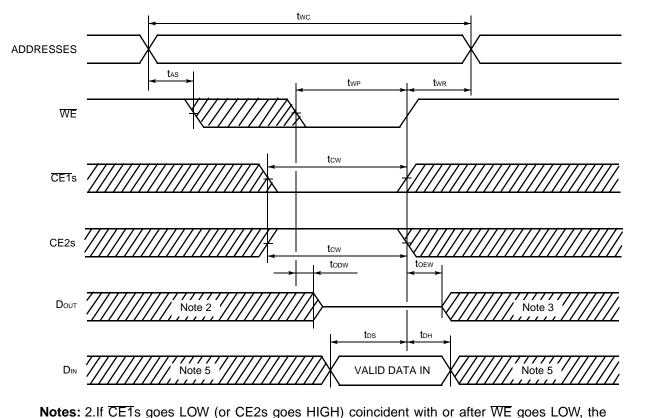


Note: 1. WE remains HIGH for the read cycle.

• Write Cycle (SRAM)

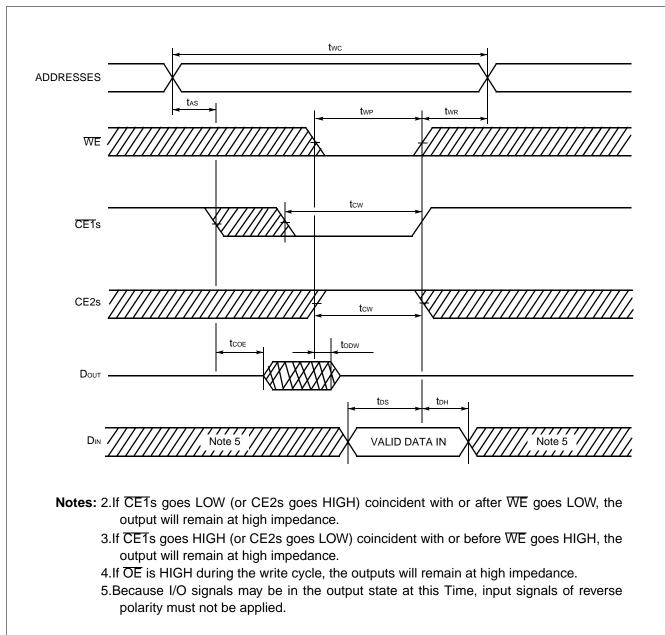
Parameter Symbol	Parameter Description	Min.	Max.	Unit
twc	Write Cycle Time	100	—	ns
twp	Write Pulse Width	60	_	ns
tcw	Chip Enable to End of Write	80	_	ns
tas	Address Setup Time	0	_	ns
twr	Write Recovery Time	0	_	ns
todw	WE Low to Output High-Z		40	ns
toew	WE High to Output Active	0	_	ns
tos	Data Setup Time	40	_	ns
tdн	Data Hold Time	0	_	ns

Write Cycle (Note 4) (WE control) (SRAM)

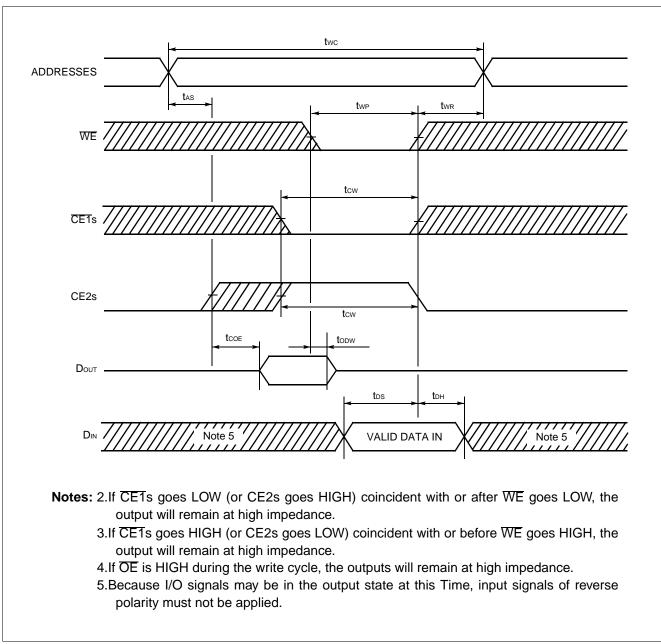


- Notes: 2.If CE1s goes LOW (or CE2s goes HIGH) coincident with or after WE goes LOW, the output will remain at high impedance.
 - 3.If CE1s goes HIGH (or CE2s goes LOW) coincident with or before WE goes HIGH, the output will remain at high impedance.
 - 4.If OE is HIGH during the write cycle, the outputs will remain at high impedance.
 - 5.Because I/O signals may be in the output state at this Time, input signals of reverse polarity must not be applied.

• Write Cycle (Note 4) (CE1s control) (SRAM)



• Write Cycle (Note 4) (CE2s Control) (SRAM)



■ ERASE AND PROGRAMMING PERFORMANCE (Flash)

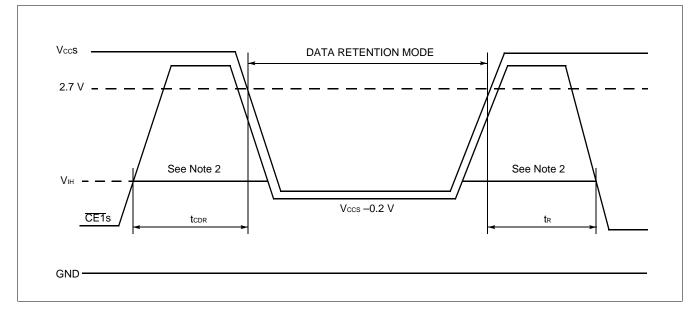
Parameter	Limits			Unit	Comment
Faranieler	Min.	Тур.	Max.	Unit	Comment
Sector Erase Time	_	1	15	sec	Excludes programming time prior to erasure
Programming Time	_	16	5,200	μs	Excludes system-level overhead
Chip Programming Time	_	16.8	100	sec	Excludes system-level overhead
Erase/Program Cycle	100,000	_	—	cycles	

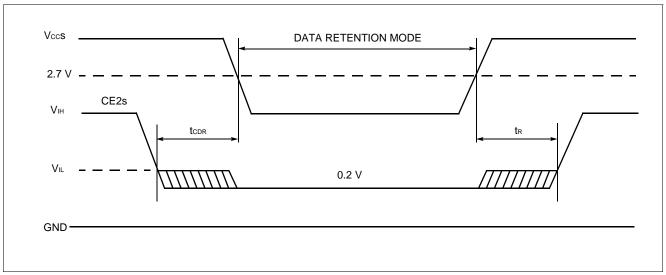
■ DATA RETENTION CHARACTERISTICS (SRAM)

Parameter Symbol	Parameter Description		Min.	Тур.	Max.	Unit
Vdh	Data Retention Supply Voltage		2.0	_	3.6	V
lasar	Standby Current	Vdh = 3.0 V		_	50*	μA
DDS2		V _{DH} = 3.6 V		_	60	μA
t cdr	Chip Deselect to Data Retention Mode Time		0	_		ns
tR	Recovery Time		5		—	ms

* : 5 μ A (Max.) at T_A = -20°C to +40°C

• CE1s Controlled Data Retention Mode (Note 1)





• CE2s Controlled Data Retention Mode (Note 3)

- Notes: 1. In CETs controlled data retention mode, input level of CE2s should be fixed Vccs to Vccs-0.2V or Vss to 0.2V during data retention mode. Other input and input/output pins can be used between -0.3V to Vccs+0.3V.
 - 2. When CE1s is operating at the V_{IH} min. level (2.2 V), the standby current is given by I_{SB1}s during the transition of V_{CCS} from 3.6 to 2.2 V.
 - 3. In CE2s controlled data retention mode, input and input/output pins can be used between -0.3V to Vccs+0.3V.

PIN CAPACITANCE

Parameter Symbol	Parameter Description	Test Setup	Тур.	Max.	Unit
CIN	Input Capacitance	V _{IN} = 0	T.B.D	T.B.D	pF
Соит	Output Capacitance	Vout = 0	T.B.D	T.B.D	pF
CIN2	Control Pin Capacitance	V _{IN} = 0	T.B.D	T.B.D	pF

Note: Test conditions $T_A = 25^{\circ}C$, f = 1.0 MHz

HANDLING OF PACKAGE

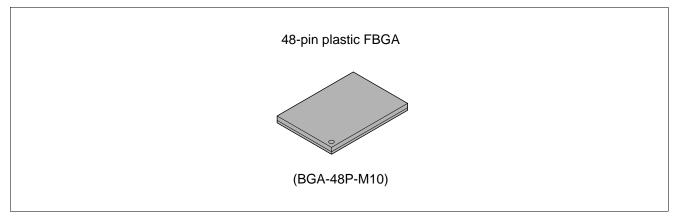
Please handle this package carefully since the sides of packages are right angle.

CAUTION

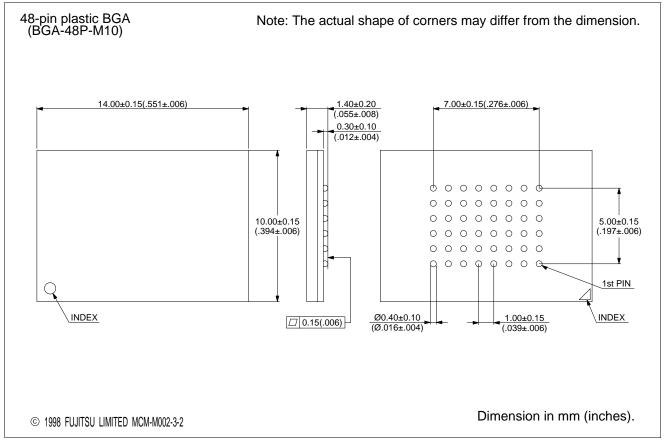
1)The high voltage (VID) can not apply to address pins and control pins except RESET. Therefore, it can not use autoselect and sector protect function by applying the high voltage (VID) to specific pins.

2)For the sector protection, since the high voltage (VID) can be applied to the RESET, it can be protected the sector useing "Extended sector protect" command.

■ PACKAGE



PACKAGE DIMENSIONS



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